

# Answer Key

*of*

# Electronics Engineering GATE-2015

**Forenoon Session**

**1st Feb, 2015**



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### Section - I (General Aptitude)

**Q.1** Choose the correct verb to fill in the blank below:

Let us \_\_\_\_\_.

- |               |               |
|---------------|---------------|
| (a) introvert | (b) alternate |
| (c) atheist   | (d) altruist  |

**Ans. (b)**

• • • **End of Solution**

**Q.2** Choose the most appropriate word from the options given below to complete the following sentence.

If the athlete had wanted to come first in the race, he \_\_\_\_\_ several hours every day.

- |                     |                           |
|---------------------|---------------------------|
| (a) should practice | (b) should have practised |
| (c) practised       | (d) should be practising  |

**Ans. (b)**

• • • **End of Solution**

**Q.3** Find the missing sequence in the letter series below:

A, CD, GHI?, UVWXY

- |          |          |
|----------|----------|
| (a) LMN  | (b) MNO  |
| (c) MNOP | (d) NOPQ |

**Ans. (c)**

• • • **End of Solution**

**Q.4** If  $x > y > 1$ , which of the following must be true?

- |                     |                        |
|---------------------|------------------------|
| (i) $\ln x > \ln y$ | (ii) $e^x > e^y$       |
| (iii) $yx > x^3$    | (iv) $\cos x > \cos y$ |
| (a) (i) and (ii)    | (b) (i) and (iii)      |
| (c) (iii) and (iv)  | (d) (ii) and (iv)      |

**Ans. (a)**

• • • **End of Solution**

**Q.5** Choose the most suitable one word substitute for the following expression:

Connection of a road or way

- |                  |              |
|------------------|--------------|
| (a) Perrinacious | (b) Viaticum |
| (c) Clandestine  | (d) Ravenous |

**Ans. (b)**

• • • **End of Solution**

**Q.6** Ms. X will be Bagdogra from 01/05/2014 to 20/05/2014 and from 22/05/2014 to 31/05/2014. On the morning of 21/05/2014, she will reach Kochi via Mumbai. Which one of the statements below is logically valid and can be inferred from the above sentences?

- (a) Ms. X will be in Kochi for one day, only in May.
- (b) Ms. X will be in Kochi for only one day in May.
- (c) Ms. X will be only in Kochi for one day in May.
- (d) Only Ms. X will be in Kochi for one day in May.

**Ans. (b)**

• • • **End of Solution**

**Q.7**  $\log \tan 1^\circ + \log \tan 2^\circ + \dots + \log \tan 89^\circ$  is \_\_\_\_\_.

- (a) 1
- (b)  $\frac{1}{\sqrt{2}}$
- (c) 0
- (d) -1

**Ans. (c)**

• • • **End of Solution**

**Q.8** In the following question, the first and the last sentence of the passage are in order and numbered 1 and 6. The rest of the passage is split into 4 parts and numbered as 2, 3, 4 and 5. These 4 parts are not arranged in proper order. Read the sentences and arrange them in a logical sequence to make a passage and choose the correct sequence from the given options.

1. On Diwali, the family rises early in the morning.
  2. The whole family, including the young and the old enjoy doing this.
  3. Children let off fireworks later in the night with their friends.
  4. At sunset, the lamps are lit and the family performs various rituals.
  5. Father, mother and children visit relatives and exchange gifts and sweets.
  6. Houses looks so pretty with lighted lamps all around.
- (a) 2, 5, 3, 4
  - (b) 5, 2, 4, 3
  - (c) 3, 5, 4, 2
  - (d) 4, 5, 2, 3

**Ans. (b)**

• • • **End of Solution**

**Q.9** Ram and Shyam shared a secret and promised to each other that it would remain between them. Ram express himself in one of the following ways as given in the choices below. Identify the correct way as per standard English.

- (a) It would remain between you and me.
- (b) It would remain between I and you.
- (c) It would remain between you and I.
- (d) It would remain with me.

**Ans. (c)**

- Q.10** From a circular sheet of paper of radius 30 cm, a sector of 10% area is removed. If the remaining part is used to make a conical surface, then the ratio of the radius and height of the cone is \_\_\_\_\_.

**Ans. (2.064)**

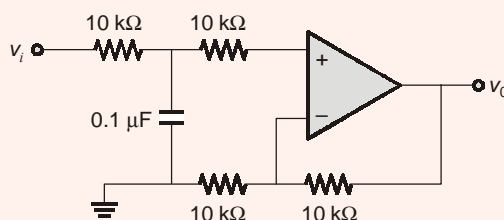
### Section - II (Electronics Engineering)

- Q.1** Consider the function  $g(t) = e^{-t} \sin(2\pi t) u(t)$  where  $u(t)$  is the unit step function. The area under  $g(t)$  is \_\_\_\_\_.

**Ans. (0.25)**

• • • **End of Solution**

- Q.2** In the circuit shown using an ideal opamp, the 3-dB cut-off frequency (in Hz) is \_\_\_\_\_.



**Ans. (159.15)**

• • • **End of Solution**

- Q.3** Which one of the following 8085 microprocessor programs correctly calculates the product of two 8-bit numbers stored in registers  $B$  and  $C$ ?

- |                 |                |
|-----------------|----------------|
| (a) MVI A, 00 H | (b) MVI A, 00H |
| JNZ LOOP        | CMP C          |
| LOOP DCR B      | LOOP DCR B     |
| HLT             | HLT            |
| (c) MVI A, 00H  | (d) MVI A, 00H |
| LOOP ADD C      | ADD C          |
| DCR B           | JNZ LOOP       |
| JNZ LOOP        | LOOP INR B     |
| HLT             | HLT            |

**Ans. (c)**

• • • **End of Solution**



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- Q.4** The contour on the  $x$ - $y$  plane, where the partial derivative of  $x^2 + y^2$  with respect to  $y$  is equal to the partial derivative of  $6y + 4x$  with respect to  $x$ , is
- (a)  $y = 2$  (b)  $x = 2$   
 (c)  $x = y = 4$  (d)  $x - y = 0$

**Ans. (a)**

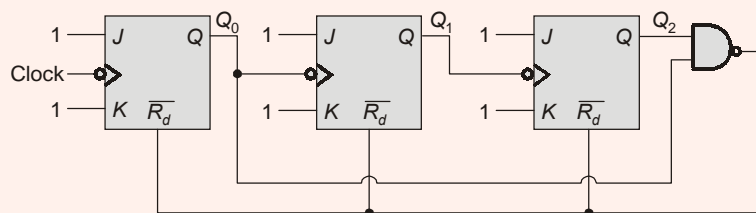
• • • End of Solution

- Q.5** The value of  $\sum_{n=0}^{\infty} n \left(\frac{1}{2}\right)^n$  is \_\_\_\_\_.

**Ans. (2)**

• • • End of Solution

- Q.6** The circuit shown consists of J-K flip-flops, each with an active low asynchronous reset ( $\overline{R_d}$  input). The counter corresponding to this circuit is



- (a) a modulo-5 binary up counter (b) a modulo-6 binary down counter  
 (c) a modulo-5 binary down counter (d) a modulo-6 binary up counter

**Ans. (a)**

• • • End of Solution

- Q.7** For  $A = \begin{bmatrix} 1 & \tan x \\ -\tan x & 1 \end{bmatrix}$ , the determinant of  $A^T A^{-1}$  is

- (a)  $\sec^2 x$  (b)  $\cos 4x$   
 (c) 1 (d) 0

**Ans. (a)**

• • • End of Solution

- Q.8** The transfer function of a first order controller is given as

$$G_C(s) = \frac{K(s + a)}{s + b}$$

where,  $K$ ,  $a$  and  $b$  are positive numbers. The condition for this controller to act as a phase lead compensator is

- (a)  $a < b$  (b)  $a < b$   
 (c)  $K < ab$  (d)  $K > ab$

Ans. (a)

• • • End of Solution

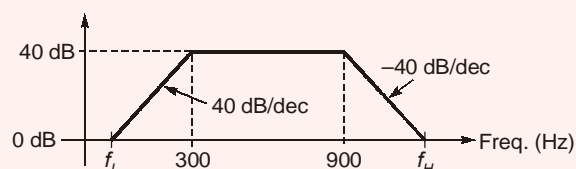
**Q.9** Which one of the following processes is preferred to form the gate dielectric (SiO<sub>2</sub>) of MOSFETs?

- (a) Sputtering (b) Molecular beam epitaxy  
 (c) Wet oxidation (d) Dry oxidation

Ans. (c)

• • • End of Solution

**Q.10** Consider the Bode plot shown in figure. Assume that all the poles and zeros are real valued.



The value of  $f_H - f_L$  (in Hz) is \_\_\_\_\_.

Ans. (8970)

• • • End of Solution

**Q.11** The directivity of an antenna array can be increased by adding more antenna elements, as a larger number of elements

- (a) improves the radiations efficiency  
 (b) increases the effective area of the antenna  
 (c) results in a better impedance matching  
 (d) allows more power to be transmitted by the antenna

Ans. (b)

• • • End of Solution

**Q.12** The modulation scheme commonly used for transmission from GSM mobile terminals is

- (a) 4-QAM  
 (b) 16-PSK  
 (c) Walsh-Hadamard orthogonal codes  
 (d) Gaussian Minimum Shift Keying (GMSK)

Ans. (d)



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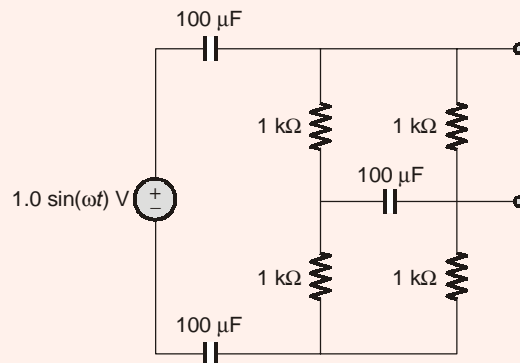
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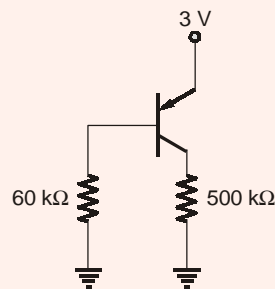
**Q.13** At very high frequencies, the peak output voltage  $V_o$  (in Volts) is \_\_\_\_\_.



**Ans. (0.5)**

• • • **End of Solution**

**Q.14** In the circuit shown in the figure, the BJT has a current gain ( $\beta$ ) of 50. For an emitter base voltage  $V_{EB} = 600$  mV, the emitter collector voltage  $V_{EC}$  (in Volts) is \_\_\_\_\_.



**Ans. (2)**

• • • **End of Solution**

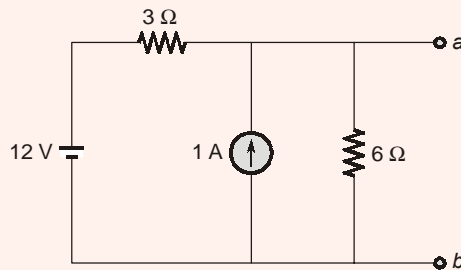
**Q.15** If the base width in a bipolar junction transistor is doubled, which one of the following statements will be TRUE?

- (a) Current gain will increase
- (b) Unity gain frequency will increase
- (c) Emitter base junction capacitance will increase
- (d) Early voltage will increase

**Ans. (d)**

• • • **End of Solution**

**Q.16** For the circuit shown in the figure, the Thevenin equivalent voltage (in Volts) across terminals  $a-b$  is \_\_\_\_\_.



Ans. (10)

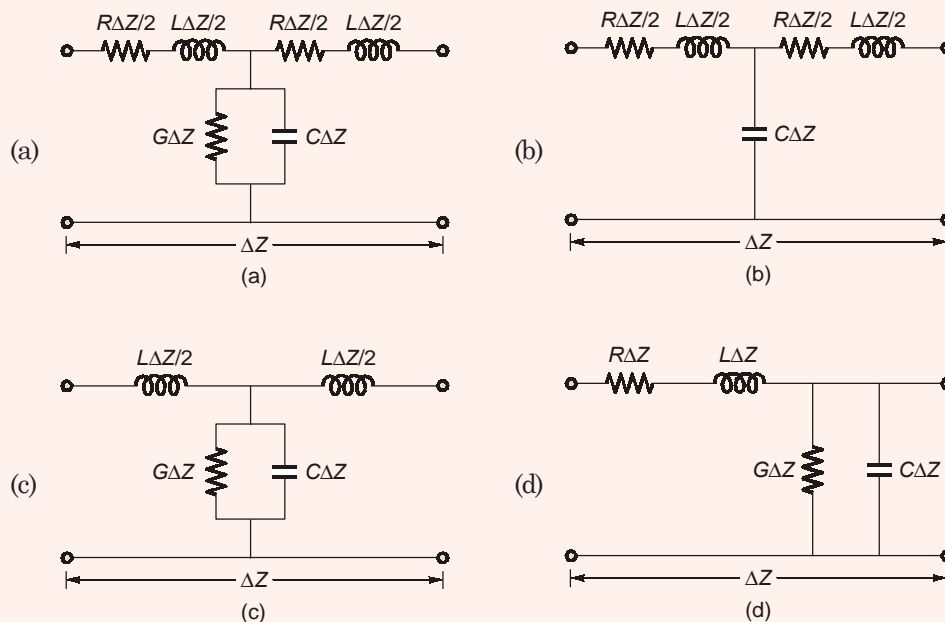
End of Solution

**Q.17** The phase margin (in degrees) of the system  $G(s) = \frac{10}{s(s+10)}$  is \_\_\_\_\_.

Ans. (45)

End of Solution

**Q.18** A coaxial cable is made of two brass conductors. The spacing between the conductors, is filled with Teflon ( $\epsilon_r = 2.1$ ,  $\tan\delta = 0$ ). Which one of the following circuits can represent the lumped element model of a small piece of this cable having length  $\Delta z$ ?



Ans. (b)

End of Solution

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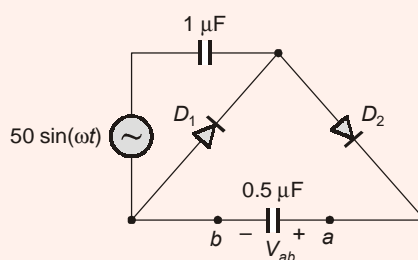
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- Q.19** The impulse response of an LTI system can be obtained by
- differentiating the unit ramp response
  - differentiating the unit step response
  - integrating the unit ramp response
  - integrating the unit step response

**Ans. (b)**

• • • **End of Solution**

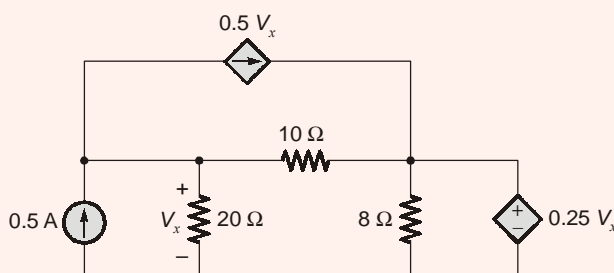
- Q.20** In the circuit shown, assume that diodes  $D_1$  and  $D_2$  are ideal. In the steady-state condition the average voltage  $V_{ab}$  (in Volts) across the  $0.5 \mu\text{F}$  capacitor is \_\_\_\_\_.



**Ans. (100)**

• • • **End of Solution**

- Q.21** In the circuit shown, the voltage  $V_x$  (in Volts) is \_\_\_\_\_.



**Ans. (8)**

• • • **End of Solution**

- Q.22** If  $C$  is a circle of radius  $r$  with center  $z_0$ , in the complex  $z$ -plane and if  $n$  is a non-zero integer, then  $\oint \frac{dz}{(z - z_0)^{n+1}}$  equals

- $2\pi nj$
- 0
- $\frac{\pi j}{2\pi}$
- $2\pi n$

**Ans. (b)**



- Q.23** A message signal  $m(t) = A_m \sin(2\pi f_m t)$  is used to modulate the phase of a carrier  $A_c \cos(2\pi f_c t)$  to get the modulated signal  $y(t) = A_c \cos(2\pi f_c t + m(t))$ . The bandwidth of  $y(t)$
- (a) depends on  $A_m$  but not on  $f_m$                       (b) depends on  $f_m$  but not on  $A_m$   
 (c) depends on both  $A_m$  and  $f_m$                       (d) does not depend on  $A_m$  or  $f_m$

**Ans. (c)**

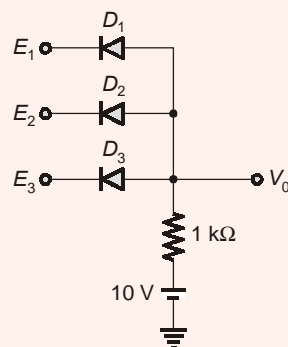
• • • **End of Solution**

- Q.24** Consider a four point moving average filter defined by the equation  $y[n] = \sum_{i=0}^3 \alpha_i x[n-i]$ . The condition on the filter coefficients that results in a null at zero frequency is
- (a)  $\alpha_1 = \alpha_2 = 0; \alpha_0 = -\alpha_3$                       (b)  $\alpha_1 = \alpha_2 = 1; \alpha_0 = -\alpha_3$   
 (c)  $\alpha_0 = \alpha_3 = 0; \alpha_1 = \alpha_2$                       (d)  $\alpha_1 = \alpha_2 = 0; \alpha_0 = \alpha_3$

**Ans. (a)**

• • • **End of Solution**

- Q.25** In the circuit shown diodes  $D_1, D_2$  and  $D_3$  are ideal, and the inputs  $E_1, E_2$  and  $E_3$  are '0 V' for logic '0' and '10 V' for logic '1'. What logic gate does the circuit represent?



- (a) 3 input OR gate                      (b) 3 input NOR gate  
 (c) 3 input AND gate                      (d) 3 input XOR gate

**Ans. (c)**

• • • **End of Solution**



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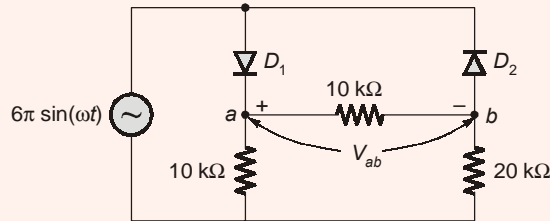
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- Q.26** In the circuit shown, assume that the diodes  $D_1$  and  $D_2$  are ideal. The average value of voltage  $V_{ab}$  (in Volts), across terminals 'a' and 'b' is \_\_\_\_\_.



**Ans. (5)**

• • • **End of Solution**

- Q.27** An universal logic gate can implement any Boolean function by connecting sufficient number of them appropriately. Three gates are shown. Which one of the following statements is TRUE?
- (a) Gate 1 is a universal gate.
  - (b) Gate 2 is a universal gate.
  - (c) Gate 3 is a universal gate.
  - (d) None of the gates shown is a universal gate.

**Ans. (d)**

• • • **End of Solution**

- Q.28** A random binary wave  $y(t)$  is given by  $y(t) = \sum_{n=-\infty}^{\infty} X_n p(t - nT - \phi)$ ,

where  $p(t) = u(t) - u(t - T)$ ,  $u(t)$  is the unit step function and  $\phi$  is an independent and identically distributed binary valued random variables with  $P\{X_n = +1\} = P\{X_n = -1\} = 0.5$  for each  $n$ .

The value of the autocorrelation  $R_{yy}\left(\frac{3T}{4}\right) \triangleq E\left[y(t)y\left(t - \frac{3T}{4}\right)\right]$  equals \_\_\_\_\_.

**Ans. (#)**

• • • **End of Solution**

- Q.29** A fair die with faces  $\{1, 2, 3, 4, 5, 6\}$  is thrown repeatedly till '3' is observed for the first time. Let  $X$  denote the number of times the die is thrown. The expected value of  $X$  is \_\_\_\_\_.

**Ans. (1)**

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**Q.34** A network is described by the state model as

$$\dot{x}_1 = 2x_1 - x_2 + 3u$$

$$\dot{x}_2 = -4x_2 - u$$

$$y = 3x_1 - 2x_2$$

The transfer function  $H(s) \left( = \frac{Y(s)}{U(s)} \right)$  is

(a)  $\frac{11s + 35}{(s - 2)(s + 4)}$

(b)  $\frac{11s - 35}{(s - 2)(s + 4)}$

(c)  $\frac{11s + 38}{(s - 2)(s + 4)}$

(d)  $\frac{11s - 38}{(s - 2)(s + 4)}$

**Ans. (a)**

• • • **End of Solution**

**Q.35** The complex envelope of the bandpass signal  $x(t) = \left( \frac{\sin(\pi t / 5)}{\pi t / 5} \right) \sin(\pi t - \frac{\pi}{4})$ ,

centered about  $f = \frac{1}{2} \text{ Hz}$ , is

(a)  $\left( \frac{\sin(\pi t / 5)}{\pi t / 5} \right) e^{j\frac{\pi}{4}}$

(b)  $\left( \frac{\sin(\pi t / 5)}{\pi t / 5} \right) e^{-j\frac{\pi}{4}}$

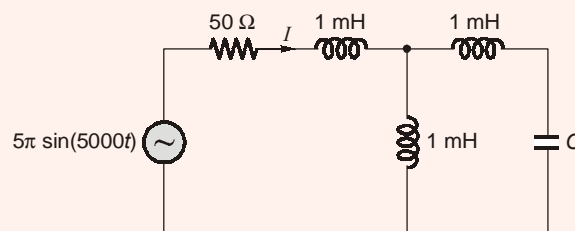
(c)  $\sqrt{2} \left( \frac{\sin(\pi t / 5)}{\pi t / 5} \right) e^{j\frac{\pi}{4}}$

(d)  $\sqrt{2} \left( \frac{\sin(\pi t / 5)}{\pi t / 5} \right) e^{-j\frac{\pi}{4}}$

**Ans. (c)**

• • • **End of Solution**

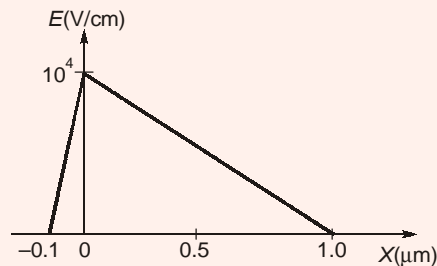
**Q.36** In the circuit shown, the current  $I$  flowing through the  $50 \Omega$  resistor will be zero if the value of capacitor  $C$  (in  $\mu\text{F}$ ) is \_\_\_\_\_.



**Ans. (20)**

• • • **End of Solution**

- Q.37** The electric field profile in the depletion region of a  $p-n$  junction in equilibrium is shown in the figure. Which one of the following statements is NOT TRUE?

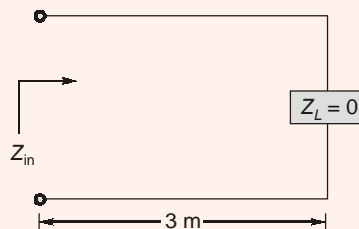


- (a) The left side of the junction is  $n$ -type and the right side is  $p$ -type
- (b) Both the  $n$ -type and  $p$ -type depletion regions are uniformly doped
- (c) The potential difference across the depletion region is 700 mV
- (d) If the  $p$ -type region has a doping concentration of  $10^{15} \text{ cm}^{-3}$ , then the doping concentration in the  $n$ -type region will be  $10^{16} \text{ cm}^{-3}$

**Ans. (c)**

• • • End of Solution

- Q.38** Consider the 3 m long lossless air-filled transmission line shown in the figure. It has a characteristic impedance of  $120 \pi \Omega$ , is terminated by a short circuit, and is excited with a frequency of 37.5 MHz. What is the nature of the input impedance ( $Z_{in}$ )?



- (a) Open
- (b) Short
- (c) Inductive
- (d) Capacitive

**Ans. (d)**

• • • End of Solution

- Q.39** Two sequences  $x_1[n]$  and  $x_2[n]$  have the same energy. Suppose  $x_1[n] = a 0.5^n u[n]$ , where  $a$  is a positive real number and  $u[n]$  is the unit step sequence. Assume

$$x_2[n] = \begin{cases} \sqrt{1.5} & \text{for } n = 0, 1 \\ 0 & \text{otherwise} \end{cases}$$

Then the value of  $a$  is \_\_\_\_.

**Ans. (1.5)**

• • • End of Solution



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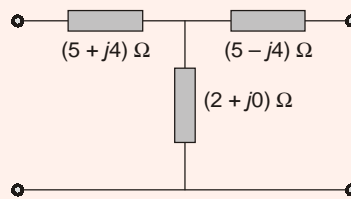
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**Q.40** The ABCD parameters of the following 2-port network are



(a)  $\begin{bmatrix} 3.5 + j2 & 20.5 \\ 20.5 & 3.5 - j2 \end{bmatrix}$

(b)  $\begin{bmatrix} 3.5 + j2 & 0.5 \\ 0.5 & 3.5 - j2 \end{bmatrix}$

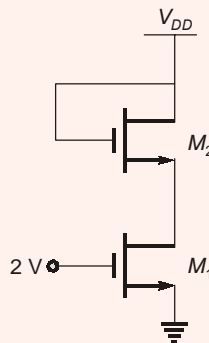
(c)  $\begin{bmatrix} 10 & 2 + j0 \\ 2 + j0 & 10 \end{bmatrix}$

(d)  $\begin{bmatrix} 7 + j4 & 0.5 \\ 30.5 & 7 - j4 \end{bmatrix}$

**Ans. (b)**

• • • **End of Solution**

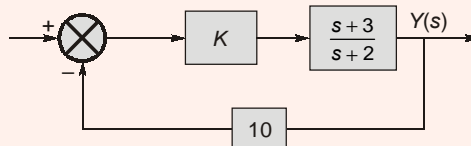
**Q.41** In the circuit shown, the both the enhancement mode NMOS transistors have the following characteristics:  $k_n = \mu_n C_{ox} (W/L) = 1 \text{ mA/V}^2$ ;  $V_{TN} = 1\text{V}$ . Assume that the channel length modulation parameter  $\lambda$  is zero and body is shorted to source. The minimum supply voltage  $V_{DD}$  (in volts) needed to ensure that transistor  $M_1$  operates in saturation mode of operation is \_\_\_\_.



**Ans. (3)**

• • • **End of Solution**

**Q.42** For the system shown in figure,  $s = -2.75$  lies on the root locus if  $K$  is \_\_\_\_.



**Ans. (0.0835)**

• • • **End of Solution**



- Q.43** The current in an enhancement mode NMOS transistor biased in saturation mode was measured to be 1 mA at a drain-source voltage of 5 V. When the drain-source voltage was increased to 6 V while keeping gate-source voltage same, the drain current increased to 1.02 mA. Assume that drain to source saturation voltages is much smaller than the applied drain-source voltage. The channel length modulation parameter  $\lambda$  (in  $V^{-1}$ ) is \_\_\_\_.

**Ans. (0.02)**

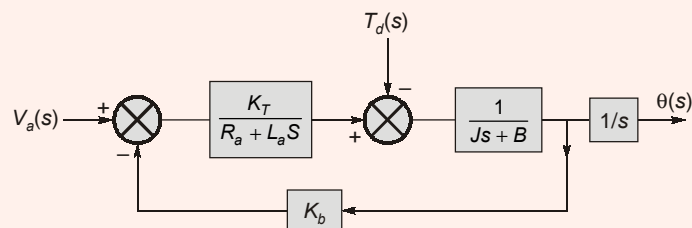
• • • **End of Solution**

- Q.44** An npn BJT having reverse saturation current  $I_s = 10^{-15}$  A is biased in the forward active region with  $V_{BE} = 700$  mV. The thermal voltage ( $V_T$ ) is 25 mV and the current gain ( $\beta$ ) may vary from 50 to 150 due to manufacturing variations. The maximum emitter current (in  $\mu$ A) is \_\_\_\_.

**Ans. (1455)**

• • • **End of Solution**

- Q.45** The position control of a DC servo-motor is given in the figure. The values of the parameters are  $K_r = 1$  N-m/A,  $R_a = 1$   $\Omega$ ,  $L_a = 0.1$  H,  $J = 5$  kg-m<sup>2</sup>,  $B = 1$  N-m/(rad/sec) and  $K_b = 1$  V/(rad/sec). The steady-state position response (in radians) due to unit impulse disturbance torque  $T_d$  is



**Ans. (0.5)**

• • • **End of Solution**

- Q.46** The Newton-Raphson method is used to solve the equation  $f(x) = x^3 - 5x^2 + 6x - 8 = 0$ . Taking the initial guess as  $x = 5$ , the solution obtained at the end of the first iteration is \_\_\_\_.

**Ans. (4.290)**

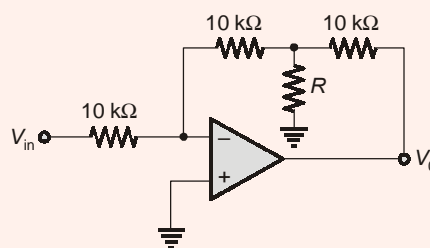
• • • **End of Solution**

- Q.47** Let  $\tilde{x}[n] = 1 + \cos\left(\frac{\pi n}{8}\right)$  be a periodic signal with period 16. Its DFS coefficients are defined by  $a_k = \frac{1}{16} \sum_{n=0}^{15} \tilde{x}[n] \exp(-j\frac{\pi}{8}kn)$  for all  $k$ . The value of the coefficient  $a_{31}$  is \_\_\_\_\_.

**Ans. (0.5)**

• • • **End of Solution**

- Q.48** In the circuit shown, assume that the opamp is ideal. If the gain  $(V_o/V_m)$  is -12, the value of  $R$  (in  $k\Omega$ ) is \_\_\_\_\_.



**Ans. (1)**

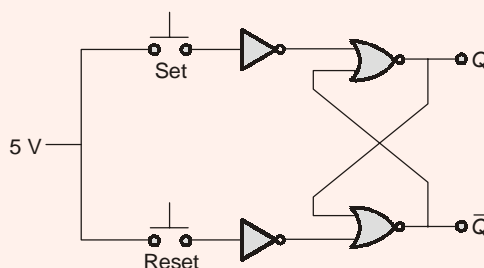
• • • **End of Solution**

- Q.49** A coaxial capacitor of inner radius 1 mm and outer radius 5 mm has a capacitance per unit length of 172 pF/m. If the ratio of outer radius to inner is doubled, the capacitance per unit length (in pF/m) is \_\_\_\_\_.

**Ans. (120.22)**

• • • **End of Solution**

- Q.50** An SR latch is implemented using TTL gates as shown in the figure. The set and reset pulse inputs are provided using the push-button switches. It is observed that the circuit fails to work as desired. The SR latch can be made functional by changing



- (a) NOR gates to NAND gates
- (b) inverters to buffers
- (c) NOR gates to NAND gates and inverters to buffers
- (d) 5 V to ground

Ans. (d)

End of Solution

**Q.51** A vector field  $D = 2 \rho_2 a_\rho + z a_z$  exists inside a cylindrical region enclosed by the surfaces  $\rho = 1$ ,  $z = 0$  and  $z = 5$ . Let  $S$  be the surface bounding this cylindrical region. The surface integral of this field on  $S$   $\oint_S D \cdot ds$  is \_\_\_\_\_.

Ans. (78.54)

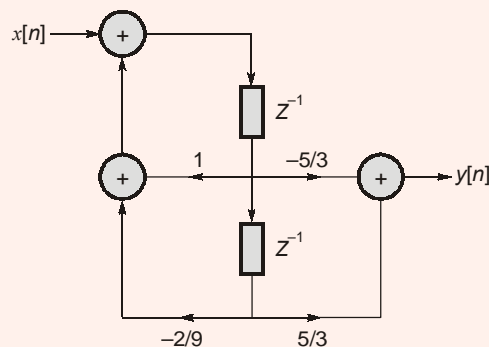
End of Solution

**Q.52** The variance of the random variable  $X$  with probability density function  $f(x) = \frac{1}{2}|x|e^{-|x|}$  is \_\_\_\_\_.

Ans. (6)

End of Solution

**Q.53** A realization of a stable discrete time system is shown in figure. If the system is excited by a unit step sequence input  $x[n]$ , the response  $y[n]$  is\_\_\_\_\_.



- (a)  $4\left(-\frac{1}{3}\right)^n u[n] - 5\left(-\frac{2}{3}\right)^n u[n]$
- (b)  $5\left(-\frac{1}{3}\right)^n u[n] - 3\left(-\frac{2}{3}\right)^n u[n]$
- (c)  $5\left(\frac{1}{3}\right)^n u[n] - 5\left(\frac{2}{3}\right)^n u[n]$
- (d)  $5\left(\frac{2}{3}\right)^n u[n] - 5\left(\frac{1}{3}\right)^n u[n]$

Ans. (c)

End of Solution

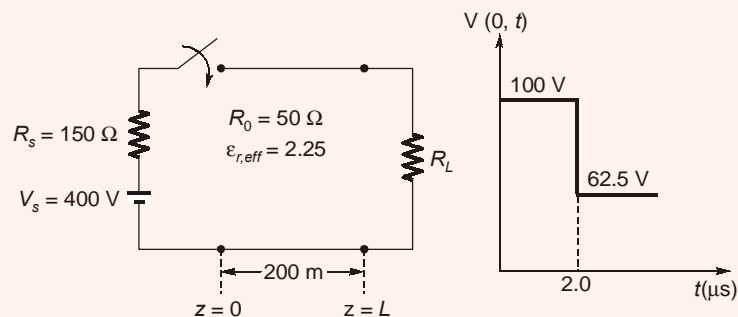


- Q.54** Consider the differential equation  $\frac{d^2x(t)}{dt^2} + 3\frac{dx(t)}{dt} + 2x(t) = 0$ . Given  $x(0) = 20$  and  $x(1) = 10/e$ , where  $e = 2.718$ , the value of  $x(2)$  is\_\_\_\_\_.

**Ans. (0.8553)**

• • • **End of Solution**

- Q.55** A 200 m long transmission line having parameters shown in the figure is terminated into a load  $R_L$ . The line is connected to a 400 V source having source resistance  $R_s$  through a switch which is closed at  $t = 0$ . The transient response of the circuit at the input of the line ( $z = 0$ ) is also drawn in the figure. The value of  $R_L$  (in  $\Omega$ ) is \_\_\_\_\_.



**Ans. (30)**

• • • **End of Solution**

